



July 1999 Revised March 2005 4LVTH273 Low Voltage Octal D-Type Flip-Flop with Clear

# 74LVTH273 Low Voltage Octal D-Type Flip-Flop with Clear

#### **General Description**

The LVTH273 is a high-speed, low-power positive-edgetriggered octal D-type flip-flop featuring separate D-type inputs for each flip-flop. A buffered Clock (CP) and Clear (CLR) are common to all flip-flops.

The state of each D-type input, one setup time before the positive clock transition, is transferred to the corresponding flip-flop's output.

The LVTH273 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal flip-flops are designed for low-voltage (3.3V) V<sub>CC</sub> applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH273 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

## **Features**

- Input and output interface capability to systems at 5V V<sub>CC</sub>
- Bushold on the data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 273
- Latch-up performance exceeds 500 mA
- ESD performance: Human-body model > 2000V Machine model > 200V Charged-device model > 1000V

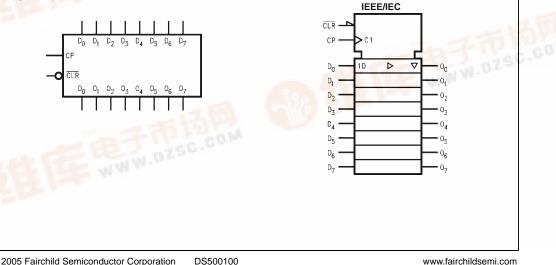
# **Ordering Code:**

Order Number	Package Number	Package Description
74LVTH273WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH273SJ	M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH273MTCX_NL (Note 1)	MTC20	Pb-Free 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

Note 1: "\_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.

# Logic Symbols







Connection Diagram							
_							
CLR -	1	20 — V <sub>CC</sub>					
°° —	2	19 — 0 <sub>7</sub>					
D <sub>0</sub> —	3	18 — D <sub>7</sub>					
D <sub>1</sub> —	4	17 — D <sub>6</sub>					
0 <sub>1</sub> —	5	16 — 0 <sub>6</sub>					
° <sub>2</sub> —	6	15 — 0 <sub>5</sub>					
D <sub>2</sub> —	7	14 — D <sub>5</sub>					
D <sub>3</sub> —	8	13 — D <sub>4</sub>					
0 <sub>3</sub> —	9	12 — 0 <sub>4</sub>					
gnd —	10	11 — CP					

#### **Pin Descriptions**

Pin Names	Description
D <sub>0</sub> -D <sub>7</sub>	Data Inputs
СР	Clock Pulse Input
CLR	Clear
O <sub>0</sub> -O <sub>7</sub>	Outputs

### **Truth Table**

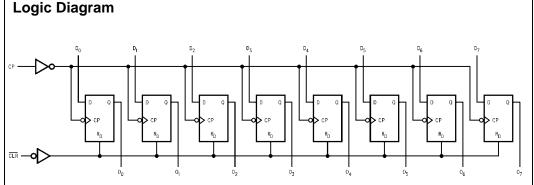
	Inputs				
D <sub>n</sub>	СР	CLR	On		
Н	~	Н	Н		
L	~	н	L		
х	H or L	н	Oo		
х	х	L	L		

H = HIGH Voltage Level L = LOW Voltage Level

$$\label{eq:constraint} \begin{split} & \mathcal{L} = \text{Immaterial} \\ \mathcal{T} = \text{LOW-to-HIGH Transition} \\ O_{\text{o}} = \text{Previous } O_{\text{o}} \text{ before HIGH-to-LOW of CP} \end{split}$$

## **Functional Description**

The LVTH273 consists of eight positive-edge-triggered flip-flops with individual D-type inputs. The buffered Clock and Clear are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. When the Clock is either HIGH or LOW, the D-input signal has no effect at the output. When the Clear ( $\overline{CLR}$ ) is LOW, all Outputs will be forced LOW.



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

# Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V <sub>CC</sub>	Supply Voltage	-0.5 to +4.6		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in HIGH or LOW State (Note 3)	V
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
I <sub>O</sub>	DC Output Current	64	$V_{O} > V_{CC}$ Output at HIGH State	mA
		128	V <sub>O</sub> > V <sub>CC</sub> Output at LOW State	IIIA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±64		mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±128		mA
T <sub>STG</sub>	Storage Temperature	-65 to +150		°C

# **Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Units	
V <sub>CC</sub>	Supply Voltage	2.7	3.6	V	
V <sub>I</sub>	Input Voltage	0	5.5	V	
он	HIGH Level Output Current		-32	mA	
OL	LOW Level Output Current		64	mA	
T <sub>A</sub>	Free-Air Operating Temperature	-40	85	°C	
Δt/ΔV	Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V	0	10	ns/V	

Note 2: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or co beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied. Note 3: I<sub>O</sub> Absolute Maximum Rating must be observed.

# **DC Electrical Characteristics**

				T <sub>A</sub> =	-40°C to +8	35°C			
Symbol	Parameter	r	V <sub>CC</sub> (V)	Min	Min Typ (Note 4)		Units	Conditions	
V <sub>IK</sub>	Input Clamp Diode Voltage	)	2.7			-1.2	V	I <sub>I</sub> = -18 mA	
V <sub>IH</sub>	Input HIGH Voltage		2.7–3.6	2.0			V	$V_0 \le 0.1V$ or	
V <sub>IL</sub>	Input LOW Voltage		2.7–3.6			0.8	V	$V_O \ge V_{CC} = 0.1V$	
V <sub>он</sub>	Output HIGH Voltage		2.7–3.6	V <sub>CC</sub> - 0.2				I <sub>OH</sub> = −100 μA	
			2.7	2.4			V	I <sub>OH</sub> = -8 mA	
			3.0	2.0				I <sub>OH</sub> = -32 mA	
V <sub>OL</sub>	Output LOW Voltage		2.7			0.2		I <sub>OL</sub> = 100 μA	
			2.7			0.5		I <sub>OL</sub> = 24 mA	
			3.0			0.4	V	I <sub>OL</sub> = 16 mA	
			3.0			0.5		I <sub>OL</sub> = 32 mA	
			3.0			0.55		I <sub>OL</sub> = 64 mA	
I(HOLD)	Bushold Input Minimum Dr	ive	3.0	75			μA	$V_{I} = 0.8V$	
				-75			μΛ	$V_{I} = 2.0V$	
I(OD)	Bushold Input Over-Drive		3.0	500			μA	(Note 5)	
	Current to Change State			-500			μΛ	(Note 6)	
l	Input Current		3.6			10	μΑ	$V_{I} = 5.5V$	
		Control Pins	3.6			±1	μA	$V_I = 0V \text{ or } V_{CC}$	
		Data Pins	3.6			-5	μA	$V_I = 0V$	
		Data Tino	0.0			1	μΑ	$V_I = V_{CC}$	
OFF	Power Off Leakage Current		0			±100	μA	$0V \leq V_{I} \text{ or } V_{O} \leq 5.5V$	
ССН	Power Supply Current		3.6			0.19	mA	Outputs HIGH	
CCL	Power Supply Current		3.6			5	mA	Outputs LOW	
۵l <sup>CC</sup>	Increase in Power Supply	Current	3.6			0.2	mA	One Input at V <sub>CC</sub> – 0.6V	
	(Note 7)						Other Inputs at V <sub>CC</sub> or GN		

# 74LVTH273

# 74LVTH273

# DC Electrical Characteristics (Continued)

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than  $V_{CC}$  or GND.

# Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V <sub>CC</sub> T <sub>A</sub> = 25 °C		Units	Conditions		
Symbol	T di difficici	(V)	Min	Тур	Max	onito	$\textbf{C}_{\textbf{L}}=\textbf{50}~\textbf{pF},~\textbf{R}_{\textbf{L}}=\textbf{500}\Omega$
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3		0.8		V	(Note 9)
V <sub>OLV</sub>	Quiet Output Minimum Dynamic VOL	3.3		-0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

# **AC Electrical Characteristics**

	Parameter							
Symbol			Vo	<sub>C</sub> = 3.3V ± 0.	.3V	$V_{CC} = 2.7V$		Units
			Min	Typ (Note 10)	Мах	Min	Max	
f <sub>MAX</sub>	Maximum Clock Frequency		150			150		MHz
t <sub>PLH</sub>	Propagation Delay		1.7		4.9	1.7	5.5	
t <sub>PHL</sub>	CP to O <sub>n</sub>		1.9		4.8	1.9	5.1	ns
t <sub>PHL</sub>	Propagation Delay	CLR to On	1.6		4.8	1.6	5.4	ns
t <sub>W</sub>	Pulse Duration		3.3			3.3		ns
t <sub>S</sub>	Setup Time	Data HIGH or LOW before CP	2.3			2.7		
		CLR HIGH before CP	2.3			2.7		ns
t <sub>H</sub>	Hold Time	Data HIGH or LOW after CP	0			0		ns

Note 10: All typical values are at V\_{CC} = 3.3V, T\_A = 25^{\circ}C.

# Capacitance (Note 11)

Symbol	Parameter	Conditions	Typical	Units			
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 0V$ , $V_I = 0V$ or $V_{CC}$	3	pF			
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 3.0V$ , $V_{O} = 0V$ or $V_{CC}$	6	pF			
Note 11: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.							

